

## **Electronic Supplementaly Information (ESI)**

### **On the Role of Local Charge Carrier Mobility in the Charge Separation Mechanism of Organic Photovoltaics**

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This supporting information presents the following contents.

**Supporting Tables S1-S4, Figures S1-S11**

## Supporting Table

**Table S1. OPV device parameters and  $\Sigma\mu$  measured by TRMC**

Polymer <sup>a</sup>	PCE (%)	V <sub>oc</sub> (V)	J <sub>sc</sub> (mAcm <sup>-2</sup> )	FF (%)	PCE/V <sub>oc</sub> (% V <sup>-1</sup> )	Solvent <sup>b</sup>	$\Sigma\mu$ blend (cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> )	$\Sigma\mu$ polymer (cm <sup>2</sup> V <sup>-1</sup> s <sup>-1</sup> )	Ref <sup>c</sup>
PCPDTBT (1:3)	3.35	0.66	11.74	43	5.08	DCB	0.050	0.19	[S1]
PCPDTBT (1:3)	5.12	0.61	15.73	53	8.39	CB / DIO	0.099		[S1]
PCDTBT (1:4)	6.10	0.88	10.60	66	6.93	DCB	0.060	0.22	[S2]
PBDTTT-CF (1:1.5)	6.22	0.75	13.56	59	8.29	DCB	0.13	0.031	[S3]
PBDTTT-CF (1:1.5)	7.40	0.75	13.56	69	9.87	CB / DIO	0.089		[S3]
PSBTBT (1:1.5)	5.10	0.68	12.70	55	7.50	DCB	0.083		[S4]
P3HT (1:1)	4.37	0.61	10.6	67	7.16	DCB	0.26	0.30	[S5]
PBTBT-C <sub>14</sub> (1:4)	2.34	0.53	9.37	48	4.42	DCB	0.16	2.3	[S6]
PQT-12 (1:4)	1.15	0.61	4.31	44	1.88	DCB	0.057	0.22	[S7]
PTzBT-BOHD (1:2)	6.65	0.89	11.35	65	7.47	CB	0.23	0.24	[S8]
PTzBT-14HD (1:2)	5.42	0.82	9.93	66	6.61	CB	0.19		[S8]
PTzBT-14OD (1:2)	5.12	0.82	9.77	64	6.24	CB	0.14		[S8]

<sup>a</sup> Polymer (p/n blend ratio with PCBM) <sup>b</sup> The solvent and additive. DCB: *o*-dichlorobenzene, CB: chlorobenzene, DIO: 1,8-diiodooctane. <sup>c</sup> Reference number of the device performance.

**Table S2. Summary of XRD measurements of polymer:PCBM blend.**

Polymer <sup>a</sup>	Inter-lamellar peak intensity (counts)	$2\theta(^{\circ})$	$d$ (nm) <sup>b</sup>	$L_{(100)}$ (nm) <sup>c</sup>
P3HT (1:1)	$3.8 \times 10^3$	5.44	1.62	18.5
PQT-12 (1:4)	$1.6 \times 10^3$	3.44	2.57	35.7
PBT TT-C <sub>14</sub> (1:4)	$2.6 \times 10^3$	3.20	2.76	14.2
PTzBT-14HD (1:2)	$1.5 \times 10^4$	4.06	2.18	10.9
PTzBT-14OD (1:2)	$2.7 \times 10^4$	3.58	2.47	16.4
PTzBT-BOHD (1:2)	$2.7 \times 10^3$	4.78	1.85	8.6
PCPDTBT (1:3)	$1.3 \times 10^2$	6.46	1.37	2.9
PCPDTBT (1:3) DIO	- <sup>d</sup>	- <sup>d</sup>	- <sup>d</sup>	- <sup>d</sup>
PSBTBT (1:2)	$4.9 \times 10^2$	5.24	1.69	7.9
PBDTTT-CF (1:1.5)	$8.5 \times 10^2$	5.38	1.64	3.7
PBDTTT-CF (1:1.5) DIO	$6.3 \times 10^2$	5.08	1.74	3.2
PCDTBT (1:4)	$1.2 \times 10^2$	5.26	1.68	4.5

<sup>a</sup> Polymer (p/n blend ratio with PCBM) with/without DIO. <sup>b</sup> Inter-lamellar distance. <sup>c</sup> Correlation length in the inter-lamellar direction calculated using Scherrer equation. <sup>d</sup> Not obtained.

**Table S3. Electrochemical properties of the polymers.**

Polymer	HOMO /eV	LUMO /eV	bandgap /eV	Normalized $\eta_{abs}$	Ref <sup>a</sup>
PCPDTBT	-5.30	-3.55	1.75	1.00	[S9]
PBDTTT-CF	-5.22	-3.45	1.77	0.97	[S10]
PCDTBT	-5.50	-3.60	1.90	0.80	[S2]
PSBTBT	-5.05	-3.27	1.78	0.96	[S4]
P3HT	-5.10	-3.10	2.00	0.68	[S11]
PQT-12	-5.10	-3.10	2.00	0.68	[S7]
PBT TT-C <sub>14</sub>	-5.10	-3.10	2.00	0.68	[S6]
PTzBT-BOHD	-5.23	-3.43	1.80	0.93	[S8]
PTzBT-14HD	-5.21	-3.41	1.80	0.93	[S8]
PTzBT-14OD	-5.21	-3.41	1.80	0.93	[S8]

<sup>a</sup> Reference number of the electrochemical properties.

**Table S4. Charge collection efficiency calculated by Hecht equation.**

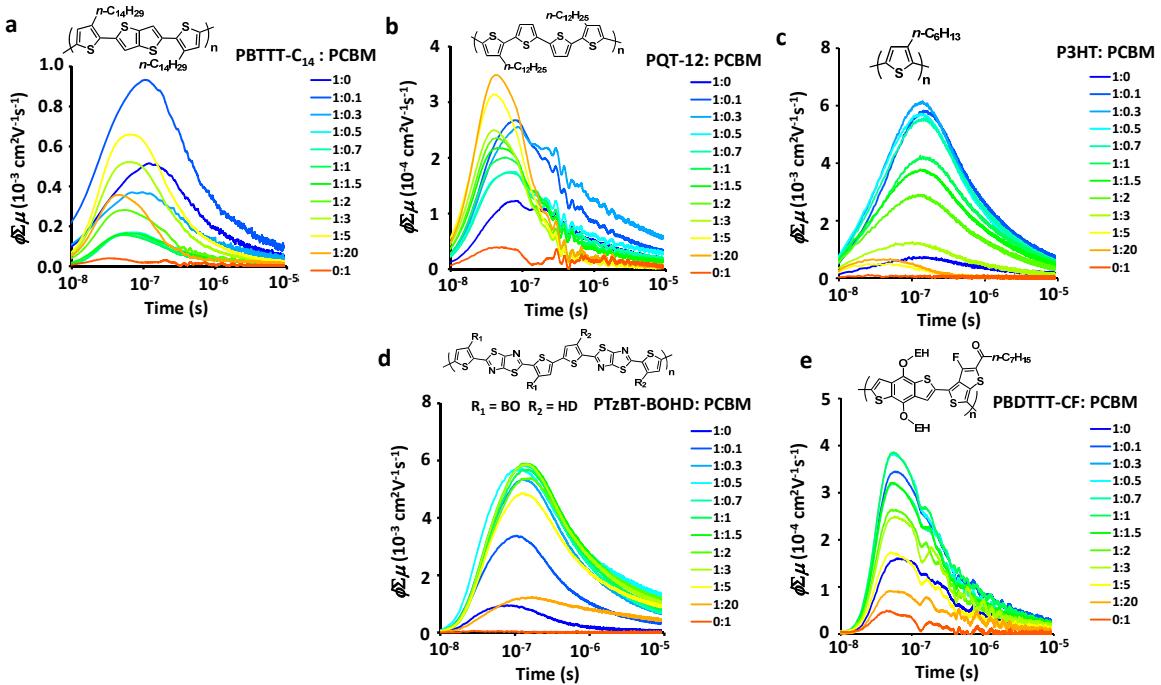
Polymer <sup>a</sup>	$\tau_{1/2}$ ( $\mu$ s) <sup>b</sup>	SCLC hole mobility ( $\text{cm}^2\text{V}^{-1}\text{s}^{-1}$ )	$V_{oc}$ (V)	Thickness (nm)	$\eta_{CC}$ <sup>c</sup>	Ref <sup>d</sup>
PCPDTBT (1:3)	0.18	$4.0 \times 10^{-4}$	0.66	100	0.62	[S12]
PBDTTT-CF (1:1)	0.22	$7.0 \times 10^{-4}$	0.76	100	0.81	[S10]
PCDTBT (1:4)	0.20	$1.5 \times 10^{-4}$ (FET)	0.90	100	0.46	[S13]
PSBTBT	0.35	$1.0 \times 10^{-3}$ (FET)	0.68	100	0.90	[S14]
P3HT (1:1)	0.50	$3.1 \times 10^{-4}$	0.61	220	0.36	[S15]
PQT-12 (1:4)	0.50	$2.7 \times 10^{-4}$	0.61	220	0.32	[S16]
PBTBT (1:4)	0.089	$3.8 \times 10^{-4}$	0.61	100	0.38	[S6]
PTzBT-BOHD (1:2)	0.22	$4.8 \times 10^{-4}$	0.53	100	0.66	[S8]
PTzBT-14HD (1:2)	0.85	$1.9 \times 10^{-4}$	0.89	200	0.54	[S8]
PTzBT-14OD (1:2)	0.95	$3.6 \times 10^{-4}$	0.82	200	0.72	[S8]

<sup>a</sup> Polymer (p/n blend ratio with PCBM). <sup>b</sup> Half-lifetime of TRMC transient excited at 355 nm<sup>c</sup>  $\eta_{CC}$  was calculated by Hecht expression<sup>S17,S18</sup> given by

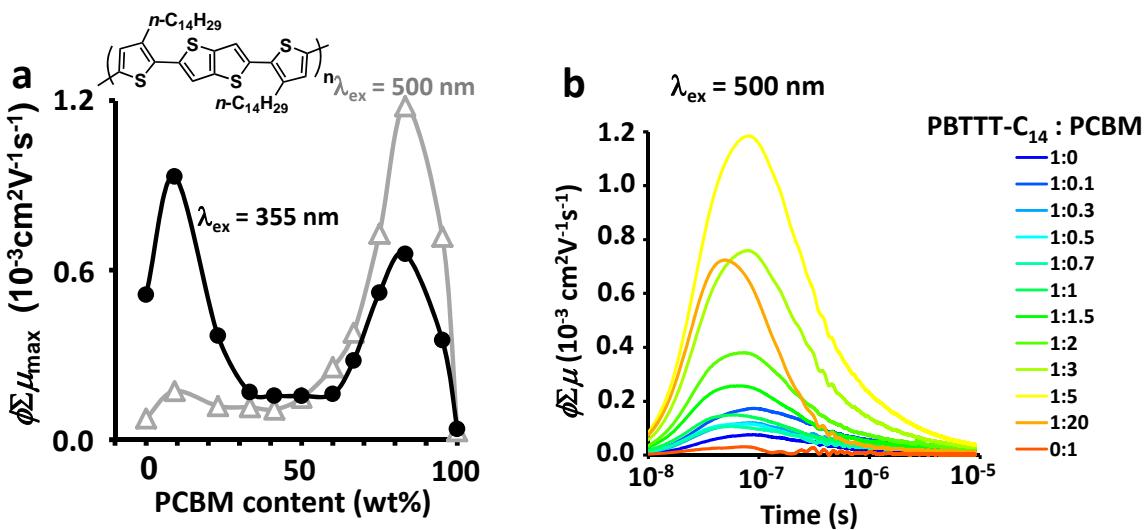
$$\eta_{CC} = \frac{\mu\tau V_b}{d \cdot d_c} \left\{ 1 - \exp\left(-\frac{d \cdot d_c}{\mu\tau V_b}\right) \right\}$$

, where  $\mu$  is the mobility,  $\tau$  is the lifetime,  $V_b$  is the internal bias voltage at the short circuit ( $= V_{oc}$ ),  $d$  is the thickness of the active layer, and  $d_c$  is the average collection length ( $= d/2$ ). <sup>d</sup> Reference number of the SCLC or FET mobilities.

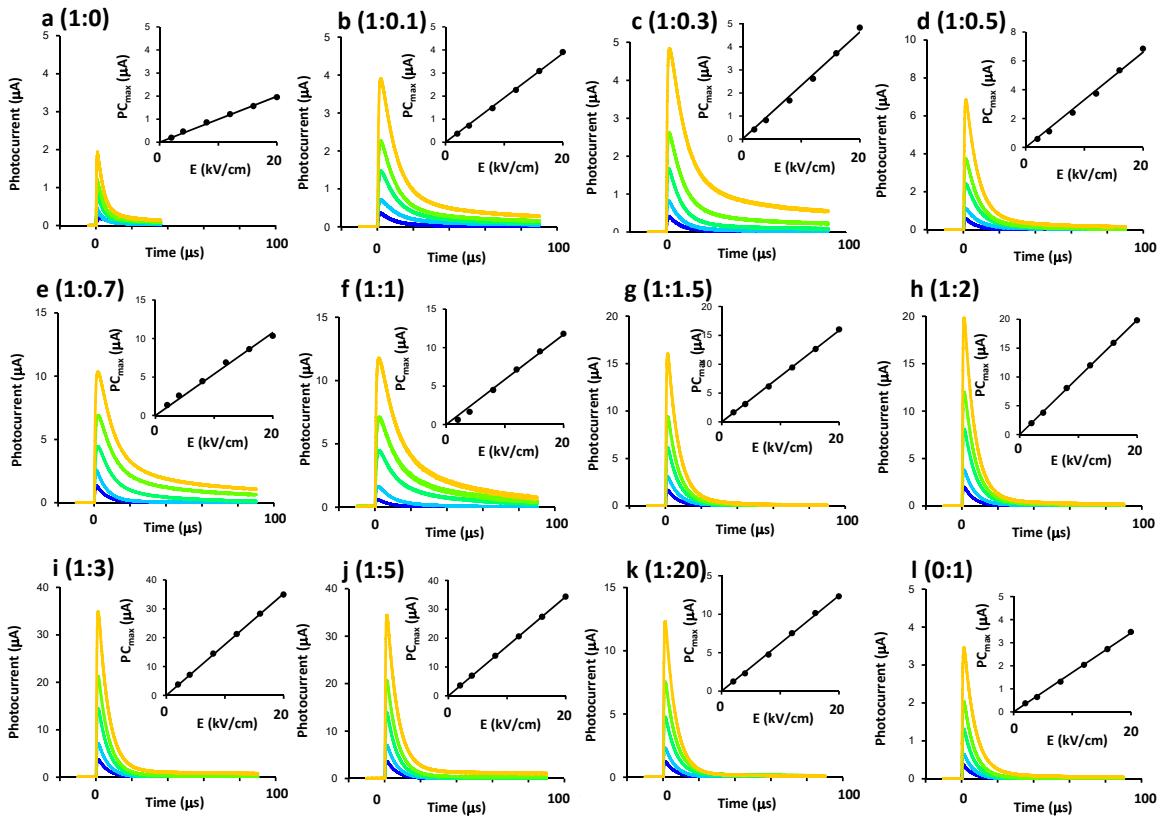
## Supporting Figures.



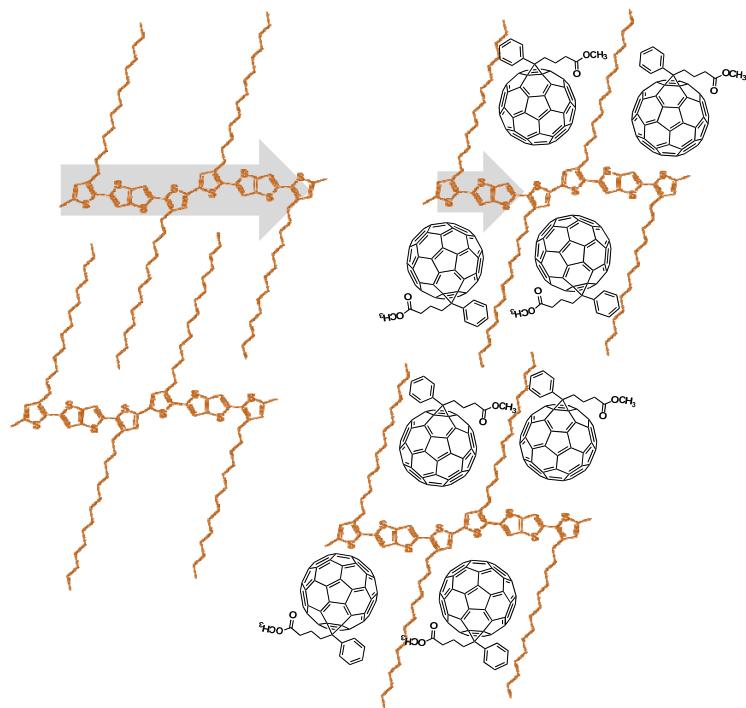
**Figure S1.** TRMC transients of a) PBTTT-C<sub>14</sub>:PCBM, b) PQT-12:PCBM, c) P3HT:PCBM, d) PTzBT-BOHD:PCBM, and e) PBDTTT-CF:PCBM blend films under 355 nm excitation. Each color line corresponds to the blend ratio shown in the inset.



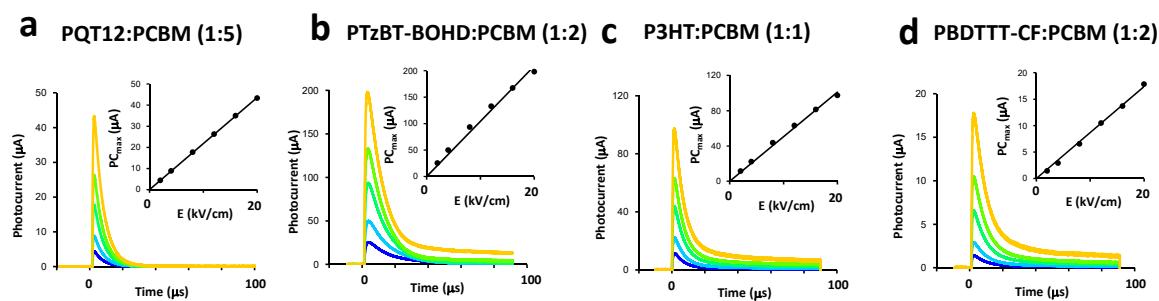
**Figure S2.** a)  $\phi \Sigma \mu_{\max}$  dependence of PBTTT-C<sub>14</sub>:PCBM on PCBM under 355 (black circles) and 500 (gray triangles) nm. b) TRMC transients of a PBTTT-C<sub>14</sub>:PCBM at 500 nm excitation. Each color line corresponds to the blend ratio shown in the inset.



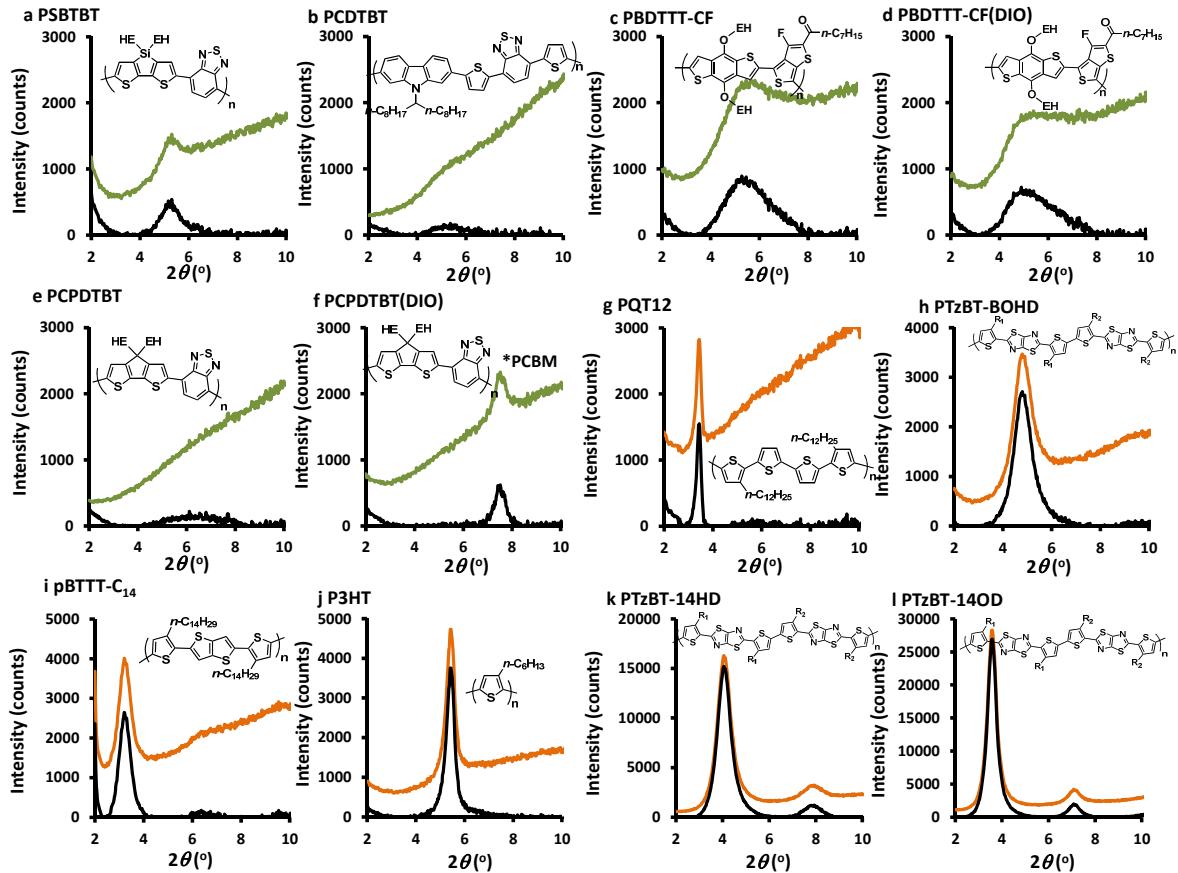
**Figure S3.** PC transients of BTTT-C<sub>14</sub>:PCBM blend films excited at 355 nm. The applied direct-current voltages are increased from blue (2 kV cm<sup>-1</sup>), green to orange (20 kV cm<sup>-1</sup>). The blend ratio of polymer and PCBM is shown in the blankets.



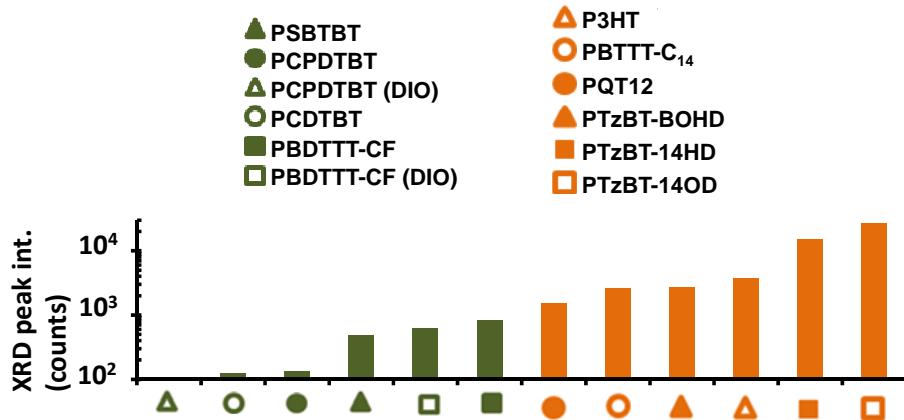
**Figure S4.** Schematic drawing of PCBM intercalation into PBTTT-C<sub>14</sub>.<sup>[S19]</sup> The gray arrows represents the degree of intramolecular hole transport.



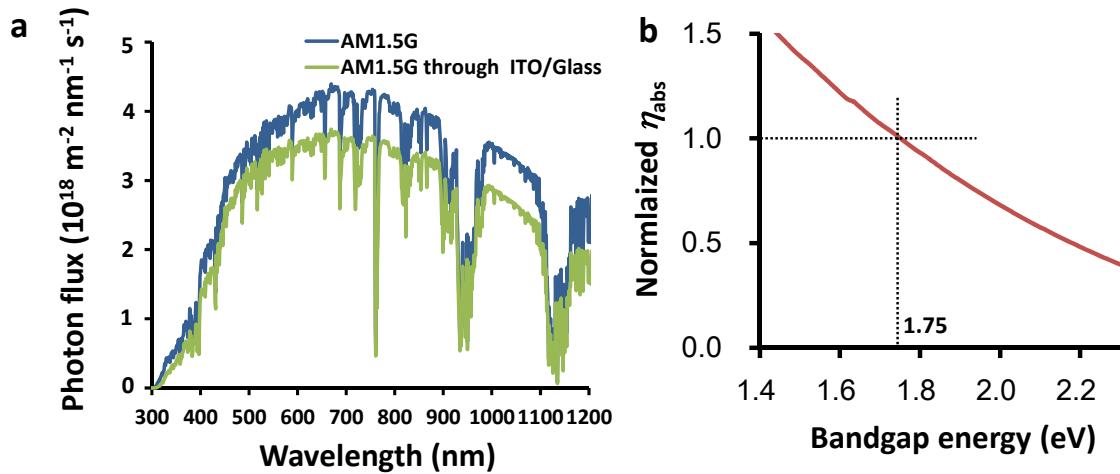
**Figure S5.** PC transients of a) PQT-12:PCBM (1:5 in wt%), b) PTzBT-BOHD:PCBM (1:2 in wt%), c) P3HT:PCBM (1:1 in wt%), and d) PBDTTT-CF:PCBM (1:2 in wt%) blend films excited at 355 nm. The applied direct-current voltages are increased from blue (2 kV cm<sup>-1</sup>), green to orange (20 kV cm<sup>-1</sup>).



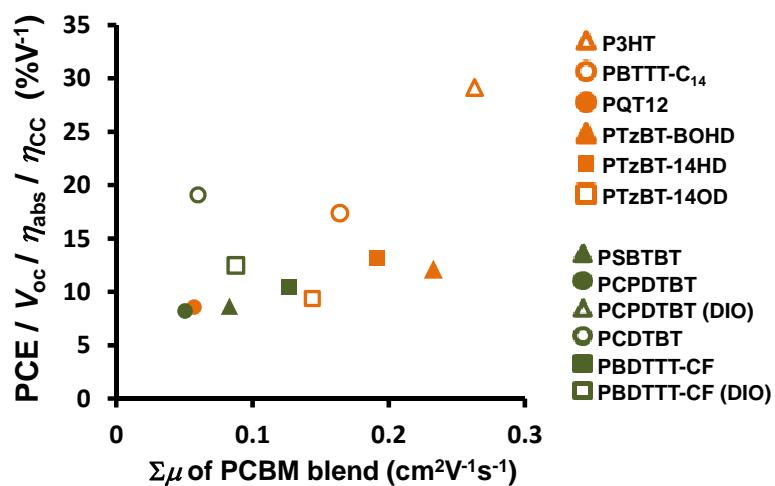
**Figure S6.** XRD spectra of polymer:PCBM films at device-optimal blend ratio in out-of-plane direction (Cu K $\alpha$ : 1.5418 Å). The colorized and black lines are the raw data and baseline-subtracted data, respectively. The peak intensities in Table S2 are based on the latter. The peak of PCPDTBT(DIO) in the panel f is due to PCBM.<sup>S20</sup>



**Figure S7.** XRD peak intensities at the inter-lamellar diffraction peaks of device-optimal polymer:PCBM blends in the out-of-plane direction.



**Figure S8.** a) AM1.5G solar spectrum (blue line) and that through a glass/ITO substrate (green line). b) Photoabsorption efficiency normalized at the bandgap energy ( $E_g$ ) of 1.75 eV (PCPDTBT). The curve was constructed by integrating the green line in a) and assuming 100% absorption of photon for  $> E_g$ .



**Figure S9.** PCE/ $V_{\text{oc}}/\eta_{\text{abs}}/\eta_{\text{CC}}$  vs. TRMC mobilities of the polymer:PCBM blends.  $\eta_{\text{CC}}$  was calculated by Hecht equation with long range mobilities of SCLC or FET. See Table S4.

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